Welcome to E-XFL.COM

Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Obsolete
Core Processor	PowerPC G4
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	1.7GHz
Co-Processors/DSP	Multimedia; SIMD
RAM Controllers	-
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	-
SATA	-
USB	-
Voltage - I/O	1.5V, 1.8V, 2.5V
Operating Temperature	0°C ~ 105°C (TA)
Security Features	-
Package / Case	360-BCBGA, FCCBGA
Supplier Device Package	360-FCCBGA (25x25)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mc7448hx1700lc

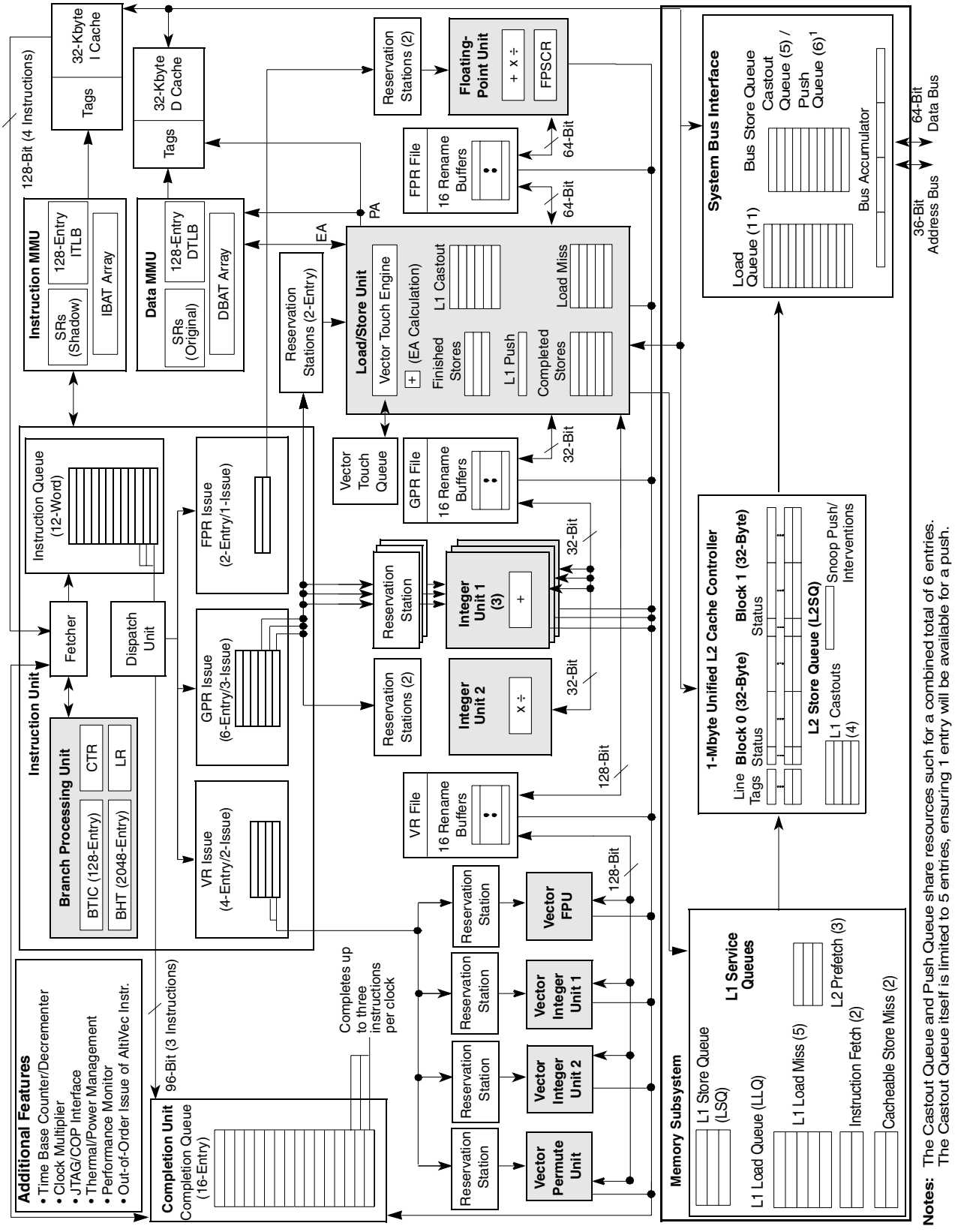


Figure 1. MPC7448 Block Diagram

2 Features

This section summarizes features of the MPC7448 implementation.

Major features of the MPC7448 are as follows:

- High-performance, superscalar microprocessor
  - Up to four instructions can be fetched from the instruction cache at a time.
  - Up to three instructions plus a branch instruction can be dispatched to the issue queues at a time.
  - Up to 12 instructions can be in the instruction queue (IQ).
  - Up to 16 instructions can be at some stage of execution simultaneously.
  - Single-cycle execution for most instructions
  - One instruction per clock cycle throughput for most instructions
  - Seven-stage pipeline control
- Eleven independent execution units and three register files
  - Branch processing unit (BPU) features static and dynamic branch prediction
    - 128-entry (32-set, four-way set-associative) branch target instruction cache (BTIC), a cache of branch instructions that have been encountered in branch/loop code sequences. If a target instruction is in the BTIC, it is fetched into the instruction queue a cycle sooner than it can be made available from the instruction cache. Typically, a fetch that hits the BTIC provides the first four instructions in the target stream.
    - 2048-entry branch history table (BHT) with 2 bits per entry for four levels of prediction—not taken, strongly not taken, taken, and strongly taken
    - Up to three outstanding speculative branches
    - Branch instructions that do not update the count register (CTR) or link register (LR) are often removed from the instruction stream.
    - Eight-entry link register stack to predict the target address of Branch Conditional to Link Register (**bclr**) instructions
  - Four integer units (IUs) that share 32 GPRs for integer operands
    - Three identical IUs (IU1a, IU1b, and IU1c) can execute all integer instructions except multiply, divide, and move to/from special-purpose register instructions.
    - IU2 executes miscellaneous instructions, including the CR logical operations, integer multiplication and division instructions, and move to/from special-purpose register instructions.
  - Five-stage FPU and 32-entry FPR file
    - Fully IEEE Std. 754™-1985–compliant FPU for both single- and double-precision operations
    - Supports non-IEEE mode for time-critical operations
    - Hardware support for denormalized numbers
    - Thirty-two 64-bit FPRs for single- or double-precision operands

- Efficient data flow
  - Although the VR/LSU interface is 128 bits, the L1/L2 bus interface allows up to 256 bits.
  - The L1 data cache is fully pipelined to provide 128 bits/cycle to or from the VRs.
  - The L2 cache is fully pipelined to provide 32 bytes per clock every other cycle to the L1 caches.
  - As many as 16 out-of-order transactions can be present on the MPX bus.
  - Store merging for multiple store misses to the same line. Only coherency action taken (address-only) for store misses merged to all 32 bytes of a cache block (no data tenure needed).
  - Three-entry finished store queue and five-entry completed store queue between the LSU and the L1 data cache
  - Separate additional queues for efficient buffering of outbound data (such as castouts and write-through stores) from the L1 data cache and L2 cache
- Multiprocessing support features include the following:
  - Hardware-enforced, MESI cache coherency protocols for data cache
  - Load/store with reservation instruction pair for atomic memory references, semaphores, and other multiprocessor operations
- Power and thermal management
  - Dynamic frequency switching (DFS) feature allows processor core frequency to be halved or quartered through software to reduce power consumption.
  - The following three power-saving modes are available to the system:
    - Nap—Instruction fetching is halted. Only the clocks for the time base, decrementer, and JTAG logic remain running. The part goes into the doze state to snoop memory operations on the bus and then back to nap using a $\overline{\text{QREQ}}$/$\overline{\text{QACK}}$ processor-system handshake protocol.
    - Sleep—Power consumption is further reduced by disabling bus snooping, leaving only the PLL in a locked and running state. All internal functional units are disabled.
    - Deep sleep—When the part is in the sleep state, the system can disable the PLL. The system can then disable the SYSCLK source for greater system power savings. Power-on reset procedures for restarting and relocking the PLL must be followed upon exiting the deep sleep state.
  - Instruction cache throttling provides control of instruction fetching to limit device temperature.
  - A new temperature diode that can determine the temperature of the microprocessor
- Performance monitor can be used to help debug system designs and improve software efficiency.
- In-system testability and debugging features through JTAG boundary-scan capability
- Testability
  - LSSD scan design
  - IEEE Std. 1149.1™ JTAG interface

- Reliability and serviceability
  - Parity checking on system bus
  - Parity checking on the L1 caches and L2 data tags
  - ECC or parity checking on L2 data

3 Comparison with the MPC7447A, MPC7447, MPC7445, and MPC7441

Table 1 compares the key features of the MPC7448 with the key features of the earlier MPC7447A, MPC7447, MPC7445, and MPC7441. All are based on the MPC7450 RISC microprocessor and are architecturally very similar. The MPC7448 is identical to the MPC7447A, but the MPC7448 supports 1 Mbyte of L2 cache with ECC and the use of dynamic frequency switching (DFS) with more bus-to-core ratios.

Table 1. Microarchitecture Comparison

Microarchitectural Specs	MPC7448	MPC7447A	MPC7447	MPC7445	MPC7441
Basic Pipeline Functions					
Logic inversions per cycle	18				
Pipeline stages up to execute	5				
Total pipeline stages (minimum)	7				
Pipeline maximum instruction throughput	3 + branch				
Pipeline Resources					
Instruction buffer size	12				
Completion buffer size	16				
Renames (integer, float, vector)	16, 16, 16				
Maximum Execution Throughput					
SFX	3				
Vector	2 (any 2 of 4 units)				
Scalar floating-point	1				
Out-of-Order Window Size in Execution Queues					
SFX integer units	1 entry × 3 queues				
Vector units	In order, 4 queues				
Scalar floating-point unit	In order				
Branch Processing Resources					
Prediction structures	BTIC, BHT, link stack				
BTIC size, associativity	128-entry, 4-way				
BHT size	2K-entry				
Link stack depth	8				
Unresolved branches supported	3				
Branch taken penalty (BTIC hit)	1				
Minimum misprediction penalty	6				

Table 1. Microarchitecture Comparison (continued)

Microarchitectural Specs	MPC7448	MPC7447A	MPC7447	MPC7445	MPC7441
Execution Unit Timings (Latency-Throughput)					
Aligned load (integer, float, vector)	3-1, 4-1, 3-1				
Misaligned load (integer, float, vector)	4-2, 5-2, 4-2				
L1 miss, L2 hit latency with ECC (data/instruction)	12/16	—			
L1 miss, L2 hit latency without ECC (data/instruction)	11/15	9/13			
SFX (add, sub, shift, rot, cmp, logicals)	1-1				
Integer multiply (32 × 8, 32 × 16, 32 × 32)	4-1, 4-1, 5-2				
Scalar float	5-1				
VSFX (vector simple)	1-1				
VCFX (vector complex)	4-1				
VFPU (vector float)	4-1				
VPER (vector permute)	2-1				
MMUs					
TLBs (instruction and data)	128-entry, 2-way				
Tablewalk mechanism	Hardware + software				
Instruction BATs/data BATs	8/8	8/8	8/8	8/8	4/4
L1 I Cache/D Cache Features					
Size	32K/32K				
Associativity	8-way				
Locking granularity	Way				
Parity on I cache	Word				
Parity on D cache	Byte				
Number of D cache misses (load/store)	5/2	5/1			
Data stream touch engines	4 streams				
On-Chip Cache Features					
Cache level	L2				
Size/associativity	1-Mbyte/ 8-way	512-Kbyte/8-way		256-Kbyte/8-way	
Access width	256 bits				
Number of 32-byte sectors/line	2	2			
Parity tag	Byte	Byte			
Parity data	Byte	Byte			
Data ECC	64-bit	—			
Thermal Control					
Dynamic frequency switching divide-by-two mode	Yes	Yes	No	No	No
Dynamic frequency switching divide-by-four mode	Yes	No	No	No	No
Thermal diode	Yes	Yes	No	No	No

4 General Parameters

The following list summarizes the general parameters of the MPC7448:

Technology	90 nm CMOS SOI, nine-layer metal	
Die size	8.0 mm × 7.3 mm	
Transistor count	90 million	
Logic design	Mixed static and dynamic	
Packages	Surface mount 360 ceramic ball grid array (HCTE)	
	Surface mount 360 ceramic land grid array (HCTE)	
	Surface mount 360 ceramic ball grid array with lead-free spheres (HCTE)	
Core power supply	1.30 V	(1700 MHz device)
	1.25 V	(1600 MHz device)
	1.20 V	(1420 MHz device)
	1.15 V	(1000 MHz device)
I/O power supply	1.5 V, 1.8 V, or 2.5 V	

5 Electrical and Thermal Characteristics

This section provides the AC and DC electrical specifications and thermal characteristics for the MPC7448.

5.1 DC Electrical Characteristics

The tables in this section describe the MPC7448 DC electrical characteristics. Table 2 provides the absolute maximum ratings. See Section 9.2, “Power Supply Design and Sequencing,” for power sequencing requirements.

Table 2. Absolute Maximum Ratings [1]

Characteristic		Symbol	Maximum Value	Unit	Notes
Core supply voltage		V_{DD}	–0.3 to 1.4	V	2
PLL supply voltage		AV_{DD}	–0.3 to 1.4	V	2
Processor bus supply voltage	I/O Voltage Mode = 1.5 V	OV_{DD}	–0.3 to 1.8	V	3
	I/O Voltage Mode = 1.8 V		–0.3 to 2.2		3
	I/O Voltage Mode = 2.5 V		–0.3 to 3.0		3
Input voltage	Processor bus	V_{in}	–0.3 to OV_{DD} + 0.3	V	4
	JTAG signals	V_{in}	–0.3 to OV_{DD} + 0.3	V	
Storage temperature range		T_{stg}	– 55 to 150	•C	

Notes:

1. Functional and tested operating conditions are given in Table 4. Absolute maximum ratings are stress ratings only and functional operation at the maximums is not guaranteed. Stresses beyond those listed may affect device reliability or cause permanent damage to the device.
2. See Section 9.2, “Power Supply Design and Sequencing” for power sequencing requirements.
3. Bus must be configured in the corresponding I/O voltage mode; see Table 3.
4. **Caution**: V_{in} must not exceed OV_{DD} by more than 0.3 V at any time including during power-on reset except as allowed by the overshoot specifications. V_{in} may overshoot/undershoot to a voltage and for a maximum duration as shown in Figure 2.

Figure 6 provides the input/output timing diagram for the MPC7448.

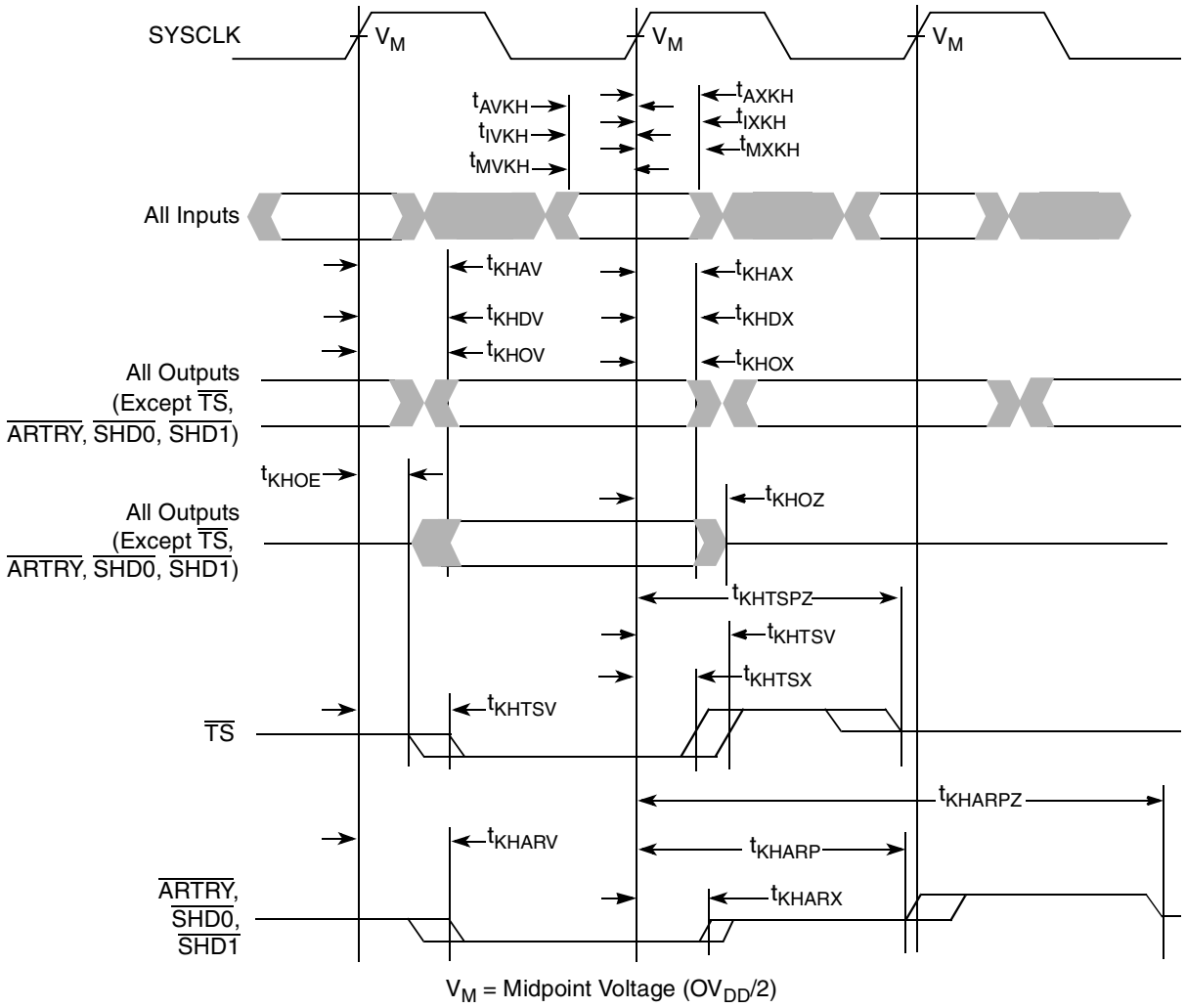
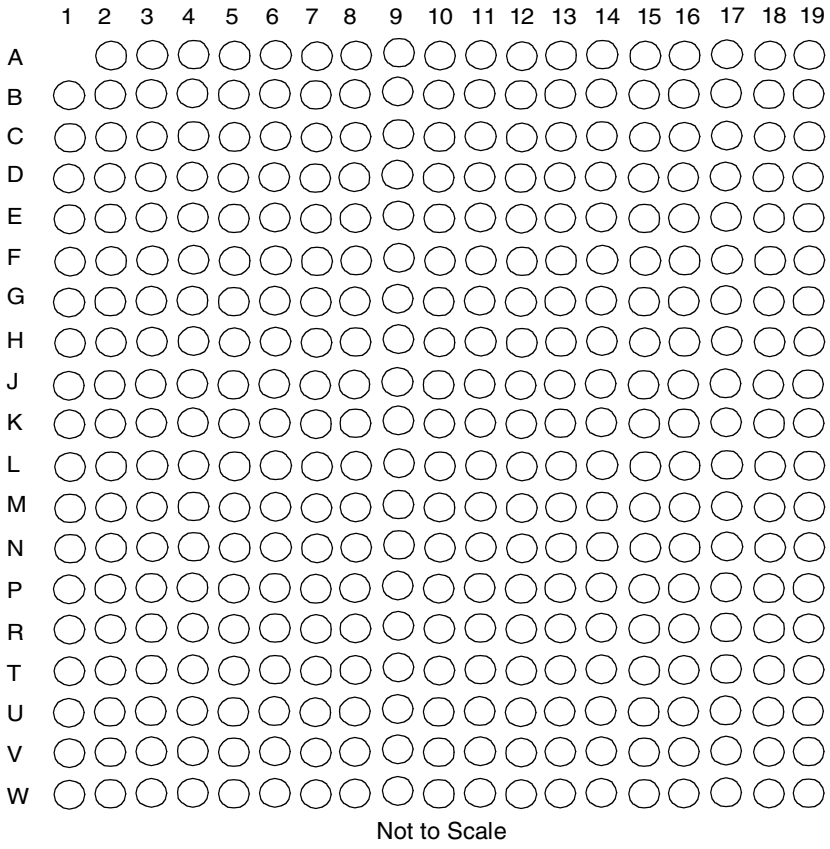


Figure 6. Input/Output Timing Diagram

6 Pin Assignments

Figure 12 (in Part A) shows the pinout of the MPC7448, 360 high coefficient of thermal expansion ceramic ball grid array (HCTE) package as viewed from the top surface. Part B shows the side profile of the HCTE package to indicate the direction of the top surface view.

Part A



Part B

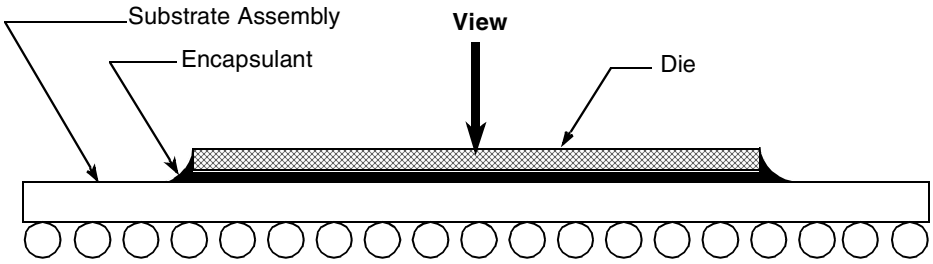


Figure 12. Pinout of the MPC7448, 360 HCTE Package as Viewed from the Top Surface

Table 11. Pinout Listing for the MPC7448, 360 HCTE Package

Signal Name	Pin Number	Active	I/O	Notes
A[0:35]	E11, H1, C11, G3, F10, L2, D11, D1, C10, G2, D12, L3, G4, T2, F4, V1, J4, R2, K5, W2, J2, K4, N4, J3, M5, P5, N3, T1, V2, U1, N5, W1, B12, C4, G10, B11	High	I/O	2
$\overline{\text{AACK}}$	R1	Low	Input	
AP[0:4]	C1, E3, H6, F5, G7	High	I/O	2
$\overline{\text{ARTRY}}$	N2	Low	I/O	3
AV_{DD}	A8	—	Input	
$\overline{\text{BG}}$	M1	Low	Input	
$\overline{\text{BMODE0}}$	G9	Low	Input	4
$\overline{\text{BMODE1}}$	F8	Low	Input	5
$\overline{\text{BR}}$	D2	Low	Output	
BVSEL0	B7	High	Input	1, 6
BVSEL1	E10	High	Input	1, 20
$\overline{\text{CI}}$	J1	Low	Output	
$\overline{\text{CKSTP\_IN}}$	A3	Low	Input	
$\overline{\text{CKSTP\_OUT}}$	B1	Low	Output	
CLK_OUT	H2	High	Output	
D[0:63]	R15, W15, T14, V16, W16, T15, U15, P14, V13, W13, T13, P13, U14, W14, R12, T12, W12, V12, N11, N10, R11, U11, W11, T11, R10, N9, P10, U10, R9, W10, U9, V9, W5, U6, T5, U5, W7, R6, P7, V6, P17, R19, V18, R18, V19, T19, U19, W19, U18, W17, W18, T16, T18, T17, W3, V17, U4, U8, U7, R7, P6, R8, W8, T8	High	I/O	
$\overline{\text{DBG}}$	M2	Low	Input	
$\overline{\text{DFS2}}$	A12	Low	Input	20, 21
$\overline{\text{DFS4}}$	B6	Low	Input	12, 20, 21
DP[0:7]	T3, W4, T4, W9, M6, V3, N8, W6	High	I/O	
$\overline{\text{DRDY}}$	R3	Low	Output	7
DTI[0:3]	G1, K1, P1, N1	High	Input	8
EXT_QUAL	A11	High	Input	9
$\overline{\text{GBL}}$	E2	Low	I/O	
GND	B5, C3, D6, D13, E17, F3, G17, H4, H7, H9, H11, H13, J6, J8, J10, J12, K7, K3, K9, K11, K13, L6, L8, L10, L12, M4, M7, M9, M11, M13, N7, P3, P9, P12, R5, R14, R17, T7, T10, U3, U13, U17, V5, V8, V11, V15	—	—	
GND	A17, A19, B13, B16, B18, E12, E19, F13, F16, F18, G19, H18, J14, L14, M15, M17, M19, N14, N16, P15, P19	—	—	15
GND_SENSE	G12, N13	—	—	19
$\overline{\text{HIT}}$	B2	Low	Output	7
$\overline{\text{HRESET}}$	D8	Low	Input	
$\overline{\text{INT}}$	D4	Low	Input	
L1_TSTCLK	G8	High	Input	9
L2_TSTCLK	B3	High	Input	10

Table 11. Pinout Listing for the MPC7448, 360 HCTE Package (continued)

Signal Name	Pin Number	Active	I/O	Notes
$\overline{\text{LVRAM}}$	B10	—	—	12, 20, 22
NC (no connect)	A6, A14, A15, B14, B15, C14, C15, C16, C17, C18, C19, D14, D15, D16, D17, D18, D19, E14, E15, F14, F15, G14, G15, H15, H16, J15, J16, J17, J18, J19, K15, K16, K17, K18, K19, L15, L16, L17, L18, L19	—	—	11
$\overline{\text{LSSD\_MODE}}$	E8	Low	Input	6, 12
$\overline{\text{MCP}}$	C9	Low	Input	
OV_{DD}	B4, C2, C12, D5, F2, H3, J5, K2, L5, M3, N6, P2, P8, P11, R4, R13, R16, T6, T9, U2, U12, U16, V4, V7, V10, V14	—	—	
OVDD_SENSE	E18, G18	—	—	16
PLL_CFG[0:4]	B8, C8, C7, D7, A7	High	Input	
PLL_CFG[5]	D10	High	Input	9, 20
$\overline{\text{PMON\_IN}}$	D9	Low	Input	13
$\overline{\text{PMON\_OUT}}$	A9	Low	Output	
$\overline{\text{QACK}}$	G5	Low	Input	
$\overline{\text{QREQ}}$	P4	Low	Output	
$\overline{\text{SHD}}$[0:1]	E4, H5	Low	I/O	3
$\overline{\text{SMI}}$	F9	Low	Input	
$\overline{\text{SRESET}}$	A2	Low	Input	
SYSCLK	A10	—	Input	
$\overline{\text{TA}}$	K6	Low	Input	
TBEN	E1	High	Input	
$\overline{\text{TBST}}$	F11	Low	Output	
TCK	C6	High	Input	
TDI	B9	High	Input	6
TDO	A4	High	Output	
$\overline{\text{TEA}}$	L1	Low	Input	
TEMP_ANODE	N18	—	—	17
TEMP_CATHODE	N19	—	—	17
TMS	F1	High	Input	6
$\overline{\text{TRST}}$	A5	Low	Input	6, 14
$\overline{\text{TS}}$	L4	Low	I/O	3
TSIZ[0:2]	G6, F7, E7	High	Output	
TT[0:4]	E5, E6, F6, E9, C5	High	I/O	
$\overline{\text{WT}}$	D3	Low	Output	
V_{DD}	H8, H10, H12, J7, J9, J11, J13, K8, K10, K12, K14, L7, L9, L11, L13, M8, M10, M12	—	—	
V_{DD}	A13, A16, A18, B17, B19, C13, E13, E16, F12, F17, F19, G11, G16, H14, H17, H19, M14, M16, M18, N15, N17, P16, P18	—	—	15

Table 11. Pinout Listing for the MPC7448, 360 HCTE Package (continued)

Signal Name	Pin Number	Active	I/O	Notes
VDD_SENSE	G13, N12	—	—	18

Notes:

1. OV_{DD} supplies power to the processor bus, JTAG, and all control signals, and is configurable. (V_{DD} supplies power to the processor core, and AV_{DD} supplies power to the PLL after filtering from V_{DD}). To program the I/O voltage, see Table 3. If used, the pull-down resistor should be less than 250 Ω. Because these settings may change in future products, it is recommended BVSEL[0:1] be configured using resistor options, jumpers, or some other flexible means, with the capability to reconfigure the termination of this signal in the future if necessary. For actual recommended value of V_{in} or supply voltages see Table 4.
2. Unused address pins must be pulled down to GND and corresponding address parity pins pulled up to OV_{DD}.
3. These pins require weak pull-up resistors (for example, 4.7 KΩ) to maintain the control signals in the negated state after they have been actively negated and released by the MPC7448 and other bus masters.
4. This signal selects between MPX bus mode (asserted) and 60x bus mode (negated) and will be sampled at $\overline{\text{HRESET}}$ going high.
5. This signal must be negated during reset, by pull-up resistor to OV_{DD} or negation by ¬$\overline{\text{HRESET}}$ (inverse of $\overline{\text{HRESET}}$), to ensure proper operation.
6. Internal pull up on die.
7. Not used in 60x bus mode.
8. These signals must be pulled down to GND if unused, or if the MPC7448 is in 60x bus mode.
9. These input signals are for factory use only and must be pulled down to GND for normal machine operation.
10. This test signal is recommended to be tied to $\overline{\text{HRESET}}$; however, other configurations will not adversely affect performance.
11. These signals are for factory use only and must be left unconnected for normal machine operation. Some pins that were NCs on the MPC7447, MPC7445, and MPC7441 have now been defined for other purposes.
12. These input signals are for factory use only and must be pulled up to OV_{DD} for normal machine operation.
13. This pin can externally cause a performance monitor event. Counting of the event is enabled through software.
14. This signal must be asserted during reset, by pull down to GND or assertion by $\overline{\text{HRESET}}$, to ensure proper operation.
15. These pins were NCs on the MPC7447, MPC7445, and MPC7441. See Section 9.3, “Connection Recommendations,” for more information.
16. These pins were OV_{DD} pins on the MPC7447, MPC7445, and MPC7441. These pins are internally connected to OV_{DD} and are intended to allow an external device (such as a power supply) to detect the I/O voltage level present inside the device package. If unused, it is recommended they be connected to test points to facilitate system debug; otherwise, they may be connected directly to OV_{DD} or left unconnected.
17. These pins provide connectivity to the on-chip temperature diode that can be used to determine the die junction temperature of the processor. These pins may be left unterminated if unused.
18. These pins are internally connected to V_{DD} and are intended to allow an external device (such as a power supply) to detect the processor core voltage level present inside the device package. If unused, it is recommended they be connected to test points to facilitate system debug; otherwise, they may be connected directly to V_{DD} or left unconnected.
19. These pins are internally connected to GND and are intended to allow an external device to detect the processor ground voltage level present inside the device package. If unused, it is recommended they be connected to test points to facilitate system debug; otherwise, they may be connected directly to GND or left unconnected.
20. These pins were in the TEST[0:4] factory test pin group on the MPC7447A, MPC7447, MPC7445, and MPC7441. They have been assigned new functions on the MPC7448.
21. These pins can be used to enable the supported dynamic frequency switching (DFS) modes via hardware. If both are pulled down, DFS mode is disabled completely and cannot be enabled via software. If unused, they should be pulled up to OV_{DD} to allow software control of DFS. See the *MPC7450 RISC Microprocessor Family Reference Manual* for more information.
22. This pin is provided to allow operation of the L2 cache at low core voltages and is for factory use only. See the *MPC7450 RISC Microprocessor Family Reference Manual* for more information.

8 Package Description

The following sections provide the package parameters and mechanical dimensions for the HCTE package.

8.1 Package Parameters for the MPC7448, 360 HCTE BGA

The package parameters are as provided in the following list. The package type is 25 × 25 mm, 360-lead high coefficient of thermal expansion ceramic ball grid array (HCTE).

Package outline	25 × 25 mm
Interconnects	360 (19 × 19 ball array – 1)
Pitch	1.27 mm (50 mil)
Minimum module height	2.32 mm
Maximum module height	2.80 mm
Ball diameter	0.89 mm (35 mil)
Coefficient of thermal expansion	12.3 ppm/°C

8.5 Package Parameters for the MPC7448, 360 HCTE RoHS-Compliant BGA

The package parameters are as provided in the following list. The package type is 25 × 25 mm, 360-lead high coefficient of thermal expansion ceramic ball grid array (HCTE) with RoHS-compliant lead-free spheres.

Package outline	25 × 25 mm
Interconnects	360 (19 × 19 ball array – 1)
Pitch	1.27 mm (50 mil)
Minimum module height	1.92 mm
Maximum module height	2.40 mm
Ball diameter	0.75 mm (30 mil)
Coefficient of thermal expansion	12.3 ppm/°C

9.1.2 System Bus Clock (SYSCLK) and Spread Spectrum Sources

Spread spectrum clock sources are an increasingly popular way to control electromagnetic interference emissions (EMI) by spreading the emitted noise to a wider spectrum and reducing the peak noise magnitude in order to meet industry and government requirements. These clock sources intentionally add long-term jitter in order to diffuse the EMI spectral content. The jitter specification given in Table 8 considers short-term (cycle-to-cycle) jitter only and the clock generator's cycle-to-cycle output jitter should meet the MPC7448 input cycle-to-cycle jitter requirement. Frequency modulation and spread are separate concerns, and the MPC7448 is compatible with spread spectrum sources if the recommendations listed in Table 13 are observed.

Table 13. Spread Spectrum Clock Source Recommendations

At recommended operating conditions. See Table 4.

Parameter	Min	Max	Unit	Notes
Frequency modulation	—	50	kHz	1
Frequency spread	—	1.0	%	1, 2

Notes:
1. Guaranteed by design
2. SYSCLK frequencies resulting from frequency spreading, and the resulting core and VCO frequencies, must meet the minimum and maximum specifications given in Table 8.

It is imperative to note that the processor's minimum and maximum SYSCLK, core, and VCO frequencies must not be exceeded regardless of the type of clock source. Therefore, systems in which the processor is operated at its maximum rated core or bus frequency should avoid violating the stated limits by using down-spreading only.

9.2 Power Supply Design and Sequencing

The following sections provide detailed information regarding power supply design for the MPC7448.

9.2.1 Power Supply Sequencing

The MPC7448 requires its power rails and clock to be applied in a specific sequence to ensure proper device operation and to prevent device damage. The power sequencing requirements are as follows:

- AV_{DD} must be delayed with respect to V_{DD} by the RC time constant of the PLL filter circuit described in Section 9.2.2, "PLL Power Supply Filtering". This time constant is nominally 100 µs.
- OV_{DD} may ramp anytime before or after V_{DD} and AV_{DD}.

Additionally, the following requirements exist regarding the application of SYSCLK:

- The voltage at the SYSCLK input must not exceed V_{DD} until V_{DD} has ramped to 0.9 V.
- The voltage at the SYSCLK input must not exceed OV_{DD} by more 20% during transients (see overshoot/undershoot specifications in Figure 2) or 0.3 V DC (see Table 2) at any time.

These requirements are shown graphically in Figure 16.

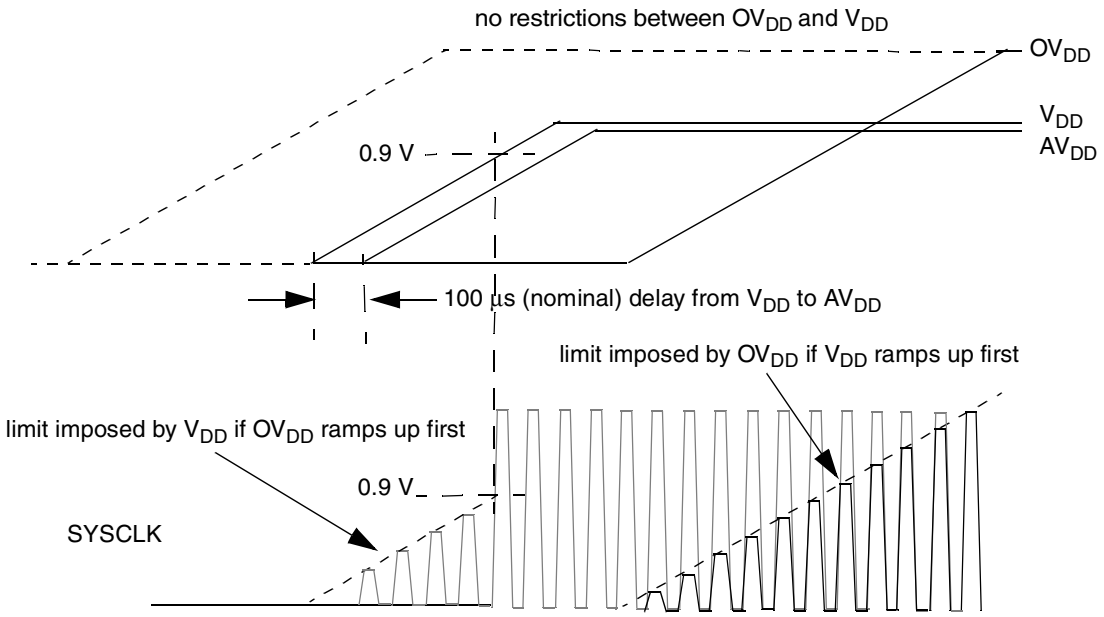


Figure 16. MPC7448 Power Up Sequencing Requirements

Certain stipulations also apply to the manner in which the power rails of the MPC7448 power down, as follows:

- OV_{DD} may ramp down any time before or after V_{DD}.
- The voltage at the SYSCLK input must not exceed V_{DD} once V_{DD} has ramped down below 0.9 V.
- The voltage at the SYSCLK input must not exceed OV_{DD} by more 20% during transients (see overshoot/undershoot specifications in Figure 2) or 0.3 V DC (see Table 2) at any time.

9.7.1 Internal Package Conduction Resistance

For the exposed-die packaging technology described in Table 5, the intrinsic conduction thermal resistance paths are as follows:

- The die junction-to-case thermal resistance (the case is actually the top of the exposed silicon die)
- The die junction-to-board thermal resistance

Figure 24 depicts the primary heat transfer path for a package with an attached heat sink mounted to a printed-circuit board.

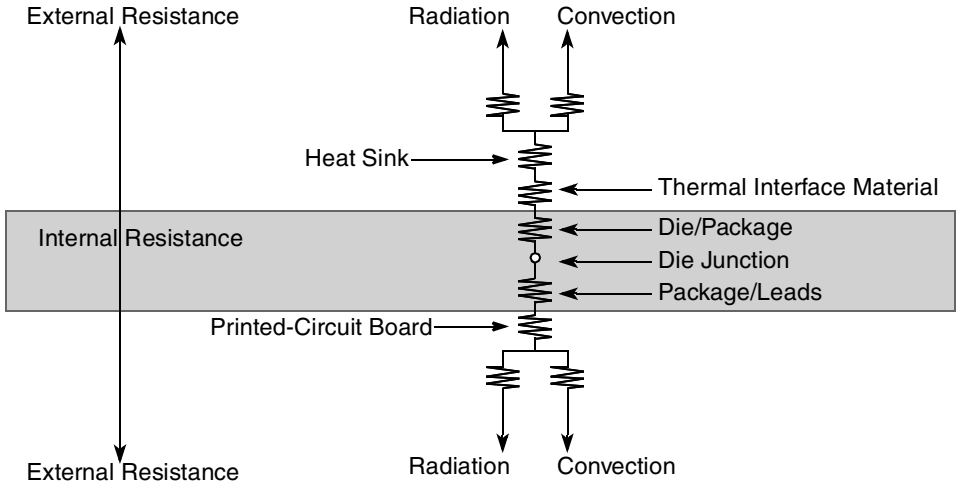


Figure 24. C4 Package with Heat Sink Mounted to a Printed-Circuit Board

Heat generated on the active side of the chip is conducted through the silicon, through the heat sink attach material (or thermal interface material), and, finally, to the heat sink, where it is removed by forced-air convection.

Because the silicon thermal resistance is quite small, the temperature drop in the silicon may be neglected for a first-order analysis. Thus, the thermal interface material and the heat sink conduction/convective thermal resistances are the dominant terms.

9.7.2 Thermal Interface Materials

A thermal interface material is recommended at the package lid-to-heat sink interface to minimize the thermal contact resistance. For those applications where the heat sink is attached by spring clip mechanism, Figure 25 shows the thermal performance of three thin-sheet thermal-interface materials (silicone, graphite/oil, fluoroether oil), a bare joint, and a joint with thermal grease as a function of contact pressure. As shown, the performance of these thermal interface materials improves with increasing contact pressure. The use of thermal grease significantly reduces the interface thermal resistance. That is, the bare joint results in a thermal resistance approximately seven times greater than the thermal grease joint.

Often, heat sinks are attached to the package by means of a spring clip to holes in the printed-circuit board (see Figure 22). Therefore, synthetic grease offers the best thermal performance due to the low interface pressure and is recommended due to the high power dissipation of the MPC7448. Of course, the selection

Due to the complexity and variety of system-level boundary conditions for today's microelectronic equipment, the combined effects of the heat transfer mechanisms (radiation, convection, and conduction) may vary widely. For these reasons, we recommend using conjugate heat transfer models for the board as well as system-level designs.

For system thermal modeling, the MPC7448 thermal model is shown in Figure 26. Four volumes represent this device. Two of the volumes, solder ball-air and substrate, are modeled using the package outline size of the package. The other two, die and bump-underfill, have the same size as the die. The silicon die should be modeled $8.0 \times 7.3 \times 0.86$ mm^3 with the heat source applied as a uniform source at the bottom of the volume. The bump and underfill layer is modeled as $8.0 \times 7.3 \times 0.07$ mm^{3}collapsed in the z-direction with a thermal conductivity of 5.0 W/(m • K) in the z-direction. The substrate volume is $25 \times 25 \times 1.14$ mm^3 and has 9.9 W/(m • K) isotropic conductivity in the xy-plane and 2.95 W/(m • K) in the direction of the z-axis. The solder ball and air layer are modeled with the same horizontal dimensions as the substrate and is 0.8 mm thick. For the LGA package the solder and air layer is 0.1 mm thick, but the material properties are the same. It can also be modeled as a collapsed volume using orthotropic material properties: 0.034 W/(m • K) in the xy-plane direction and 11.2 W/(m • K) in the direction of the z-axis.

Conductivity	Value	Unit
Die ($8.0 \times 7.3 \times 0.86$ mm^3)		
Silicon	Temperature-dependent	W/(m • K)
Bump and Underfill ($8.0 \times 7.3 \times 0.07$ mm^3)		
k_z	5.0	W/(m • K)
Substrate ($25 \times 25 \times 1.14$ mm^3)		
k_x	9.9	W/(m • K)
k_y	9.9	
k_z	2.95	
Solder Ball and Air ($25 \times 25 \times 0.8$ mm^3)		
k_x	0.034	W/(m • K)
k_y	0.034	
k_z	11.2	

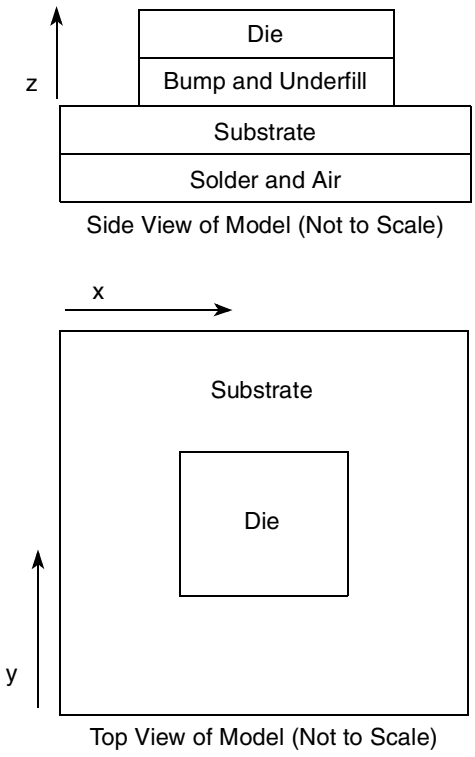


Figure 26. Recommended Thermal Model of MPC7448

9.7.4 Temperature Diode

The MPC7448 has a temperature diode on the microprocessor that can be used in conjunction with other system temperature monitoring devices (such as Analog Devices, ADT7461™). These devices use the negative temperature coefficient of a diode operated at a constant current to determine the temperature of the microprocessor and its environment. For proper operation, the monitoring device used should auto-calibrate the device by canceling out the V_{BE} variation of each MPC7448's internal diode.

The following are the specifications of the MPC7448 on-board temperature diode:

$V_f > 0.40$ V

$V_f < 0.90$ V

Operating range 2–300 µA

Diode leakage < 10 nA @ 125°C

Ideality factor over 5–150 µA at 60°C: n = 1.0275 ± 0.9%

Ideality factor is defined as the deviation from the ideal diode equation:

$$I_{fw} = I_s \left[e^{\frac{qV_f}{nKT}} - 1 \right]$$

Another useful equation is:

$$V_H - V_L = n\frac{KT}{q}\left[ln\frac{I_H}{I_L} \right] - 1$$

Where:

I_{fw} = Forward current
I_s = Saturation current
V_d = Voltage at diode
V_f = Voltage forward biased
V_H = Diode voltage while I_H is flowing
V_L = Diode voltage while I_L is flowing
I_H = Larger diode bias current
I_L = Smaller diode bias current
q = Charge of electron (1.6×10^{-19} C)
n = Ideality factor (normally 1.0)
K = Boltzman's constant (1.38×10^{-23} Joules/K)
T = Temperature (Kelvins)

The ratio of I_H to I_L is usually selected to be 10:1. The previous equation simplifies to the following:

$$V_H - V_L = 1.986 \times 10^{-4} \times nT$$

Table 16. Valid Divide Ratio Configurations

DFS mode disabled		DFS divide-by-2 mode enabled (HID1[DFS2] = 1 or $\overline{\text{DFS2}}$ = 0)		DFS divide-by-4 mode enabled (HID1[DFS4] = 1 or $\overline{\text{DFS4}}$ = 0)	
Bus-to-Core Multiplier Configured by PLL_CFG[0:5] (see Table 12)	HID1[PC0-5] [3]	Bus-to-Core Multiplier	HID1[PC0-5] [3]	Bus-to-Core Multiplier	HID1[PC0-5] [3]
2x [4]	010000	N/A (unchanged) [1]	unchanged [1]	N/A (unchanged) [1]	unchanged [1]
3x [4]	100000	N/A (unchanged) [1]	unchanged [1]	N/A (unchanged) [1]	unchanged [1]
4x [4]	101000	2x [4]	010000	N/A (unchanged) [1]	unchanged [1]
5x	101100	2.5x [4]	010101	N/A (unchanged) [1]	unchanged [1]
5.5x	100100	2.75x [4]	110101 [2]	N/A (unchanged) [1]	unchanged [1]
6x	110100	3x [4]	100000	N/A (unchanged) [1]	unchanged [1]
6.5x	010100	3.25x [4]	100000 [2]	N/A (unchanged) [1]	unchanged [1]
7x	001000	3.5x [4]	110101	N/A (unchanged) [1]	unchanged [1]
7.5x	000100	3.75x [4]	110101 [2]	N/A (unchanged) [1]	unchanged [1]
8x	110000	4x [4]	101000 [4]	2x [4]	010000
8.5x	011000	4.25x [4]	101000 [2]	N/A (unchanged) [1]	unchanged [1]
9x	011110	4.5x [4]	011101	2.25x [4]	010000 [2]
9.5x	011100	4.75x [4]	011101 [2]	N/A (unchanged) [1]	unchanged [1]
10x	101010	5x	101100	2.5x [4]	010101
10.5x	100010	5.25x	101100 [2]	N/A (unchanged) [1]	unchanged [1]
11x	100110	5.5x	100100	2.75x [4]	010101 [2]
11.5x	000000	5.75x	100100 [2]	N/A (unchanged) [1]	unchanged [1]
12x	101110	6x	110100	3x [4]	100000
12.5x	111110	6.25x	110100 [2]	N/A (unchanged) [1]	unchanged [1]
13x	010110	6.5x	010100	3.25x [4]	100000 [2]
13.5x	111000	6.75	010100 [2]	N/A (unchanged) [1]	unchanged [1]
14x	110010	7x	001000	3.5x [4]	110101
15x	000110	7.5x	000100	3.75x [4]	110101 [2]
16x	110110	8x	110000	4x [4]	101000
17x	000010	8.5x	011000	4.25x [4]	101000 [2]
18x	001010	9x	011110	4.5x [4]	011101
20x	001110	10x	101010	5x	101100
21x	010010	10.5x	100010	5.25x	101100 [2]

11 Part Numbering and Marking

Ordering information for the part numbers fully covered by this specification document is provided in Section 11.1, "Part Numbers Fully Addressed by This Document." Note that the individual part numbers correspond to a maximum processor core frequency. For available frequencies, contact a local Freescale sales office. In addition to the processor frequency, the part numbering scheme also includes an application modifier that may specify special application conditions. An optional specification modifier may also apply for parts to indicate a specific change in specifications, such as support for an extended temperature range. Finally, each part number contains a revision level code that refers to the die mask revision number. Section 11.2, "Part Numbers Not Fully Addressed by This Document," lists the part numbers that do not fully conform to the specifications of this document. These special part numbers require an additional document called a hardware specification addendum.

11.1 Part Numbers Fully Addressed by This Document

Table 18 provides the Freescale part numbering nomenclature for the MPC7448 part numbers fully addressed by this document. For information regarding other MPC7448 part numbers, see Section 11.2, "Part Numbers Not Fully Addressed by This Document."

Table 18. Part Numbering Nomenclature

xx	**7448**	***xx***	***nnnn***	**L**	***x***
Product Code	**Part Identifier**	**Package**	**Processor Frequency**	**Application Modifier**	**Revision Level**
MC PPC [1]	7448	HX = HCTE BGA VS = RoHS LGA VU = RoHS BGA	1700	L: 1.3 V +20/–50 mV 0 to 105 °C	C: 2.1; PVR = 0x8004_0201 D: 2.2; PVR = 0x8004_0202
			1600	L: 1.25 V ± 50 mV 0 to 105 °C	
			1420	L: 1.2 V ± 50 mV 0 to 105 °C	
			1000	L: 1.15 V ± 50 mV 0 to 105 °C	

Notes:

1. The P prefix in a Freescale part number designates a "Pilot Production Prototype" as defined by Freescale SOP 3-13. These parts have only preliminary reliability and characterization data. Before pilot production prototypes may be shipped, written authorization from the customer must be on file in the applicable sales office acknowledging the qualification status and the fact that product changes may still occur as pilot production prototypes are shipped.